



2818
JFw
Docket No.: 247627US2SRD DIV

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COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

RE: Application Serial No.: 10/771,537

Applicants: Yoshiaki SAITO, et al.

Filing Date: February 5, 2004

For: MAGNETIC MEMORY

Group Art Unit: 2818

Examiner: Nguyen, T.T.

SIR:

Attached hereto for filing are the following papers:

AMENDMENT, TERMINAL DISCLAIMER

Our credit card payment form in the amount of **\$110.00** is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

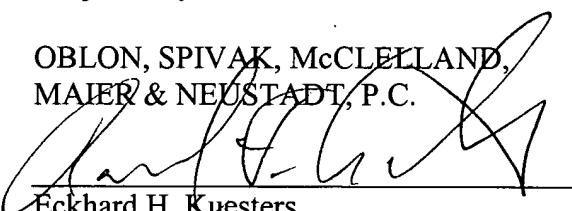
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Respectfully submitted,

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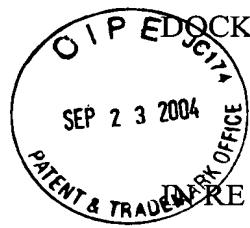
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IN THE UNITED STATES PATENT & TRADEMARK OFFICE

RE APPLICATION OF

YOSHIAKI SAITO, ET AL.

: EXAMINER: NGUYEN, T.T.

SERIAL NO: 10/771,537

:

FILED: FEBRUARY 5, 2004

: GROUP ART UNIT: 2818

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AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated June 23, 2004, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Remarks/Arguments begin on page 3 of this paper.